

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







# BC639; BCP56; BCX56

# 80 V, 1 A NPN medium power transistors Rev. 08 — 22 June 2007

**Product data sheet** 

#### **Product profile**

#### 1.1 General description

NPN medium power transistor series.

Table 1. **Product overview** 

Type number[1]	Package	Package		
	NXP	JEITA	JEDEC	
BC639[2]	SOT54	SC-43A	TO-92	BC640
BCP56	SOT223	SC-73	-	BCP53
BCX56	SOT89	SC-62	TO-243	BCX53

<sup>[1]</sup> Valid for all available selection groups.

#### 1.2 Features

- High current
- Two current gain selections
- High power dissipation capability

#### 1.3 Applications

- Linear voltage regulators
- Low-side switches
- MOSFET drivers
- Amplifiers

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	80	V
$I_{C}$	collector current		-	-	1	Α
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	1.5	Α
h <sub>FE</sub>	DC current gain	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	63	-	250	
	h <sub>FE</sub> selection -10	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	63	-	160	
	h <sub>FE</sub> selection -16	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	100	-	250	



<sup>[2]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2).

# 2. Pinning information

Pin	Pinning  Description	Simplified outline Symbol
SOT54	Dosonphon	Ompanica dutine dynibol
1	base	
2	collector	2
3	emitter	
3	ennuei	001aab347 1 3 sym056
SOT54A		
1	base	
2	collector	2
3	emitter	1 1 2 3 3 3 3 3 sym056
SOT54 va	ariant	
1	base	
2	collector	2
3	emitter	001aab447 1 1 3 sym056
SOT223		
1	base	
2	collector	4 2, 4
3	emitter	1—[
4	collector	1 2 3 3 sym016
SOT89		
1	emitter	
2	collector	2
3	base	3 3 1 sym042

# **Ordering information**

Table 4. **Ordering information** 

Type number[1]	Package					
	Name	Description	Version			
BC639 <sup>[2]</sup>	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
BCP56	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			
BCX56	SC-62	plastic surface-mounted package; collector pad for good heat transfer; 3 leads	SOT89			

<sup>[1]</sup> Valid for all available selection groups.

#### **Marking** 4.

Table 5. **Marking codes** 

Type number	Marking code
BC639	C639
BC639-10	C63910
BC639-16	C63916
BCP56	BCP56
BCP56-10	BCP56/10
BCP56-16	BCP56/16
BCX56	ВН
BCX56-10	ВК
BCX56-16	BL

<sup>[2]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

### 5. Limiting values

Table 6. Limiting values

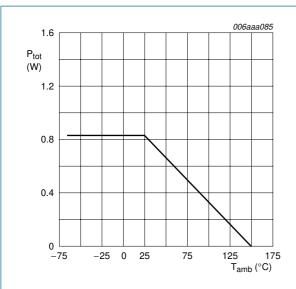
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	100	V
$V_{CEO}$	collector-emitter voltage	open base	-	80	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	1	Α
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	1.5	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	0.2	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	BC639		<u>[1]</u> -	0.83	W
	BCP56		<u>[1]</u> -	0.64	W
			[2] _	0.96	W
	BCX56		<u>[1]</u> -	0.5	W
			[2] _	0.85	W
			[3] _	1.25	W
$T_j$	junction temperature		-	150	°C
$T_{amb}$	ambient temperature		-65	+150	°C
$T_{stg}$	storage temperature		-65	+150	°C
		· · · · · · · · · · · · · · · · · · ·			

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

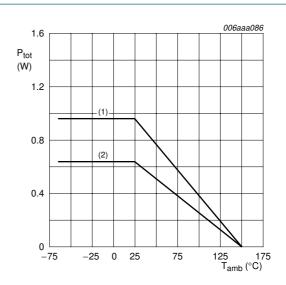
<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



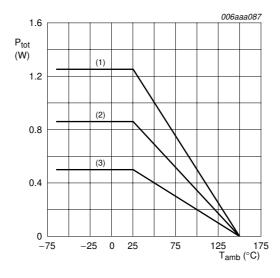
FR4 PCB, standard footprint

Fig 1. Power derating curve SOT54



- (1) FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>
- (2) FR4 PCB, standard footprint

Fig 2. Power derating curves SOT223



- (1) FR4 PCB, mounting pad for collector 6 cm<sup>2</sup>
- (2) FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>
- (3) FR4 PCB, standard footprint

#### Fig 3. Power derating curves SOT89

#### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	BC639		<u>[1]</u> -	-	150	K/W
	BCP56		<u>[1]</u> -	-	195	K/W
			[2] _	-	130	K/W
	BCX56		<u>[1]</u> -	-	250	K/W
			[2] _	-	145	K/W
			[3] _	-	100	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point					
	BC639		-	-	40	K/W
	BCP56		-	-	17	K/W
	BCX56		-	-	30	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

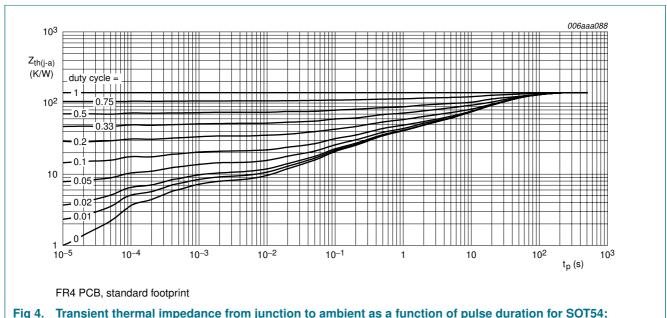
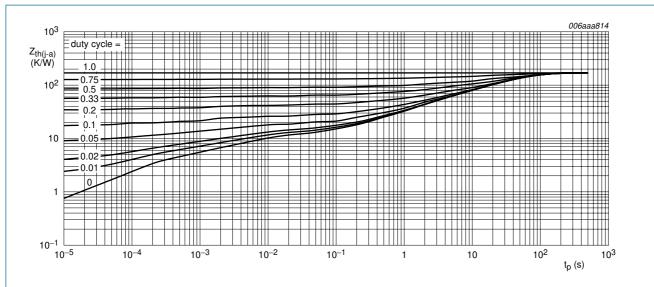
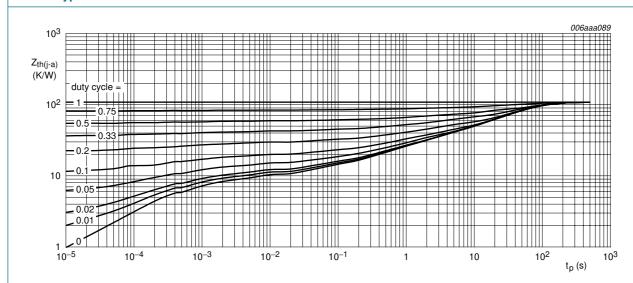


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT54; typical values



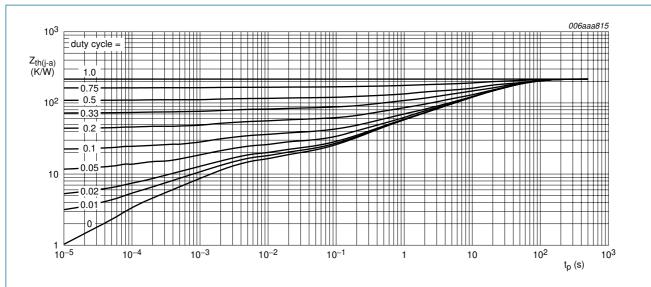
FR4 PCB, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



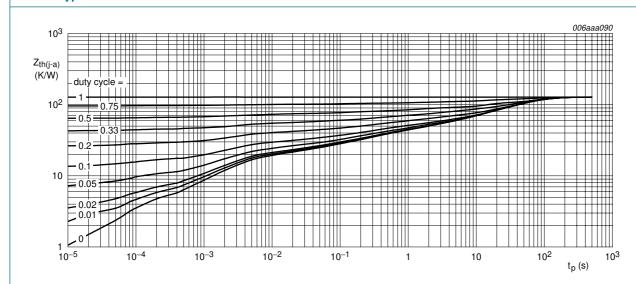
FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



FR4 PCB, standard footprint

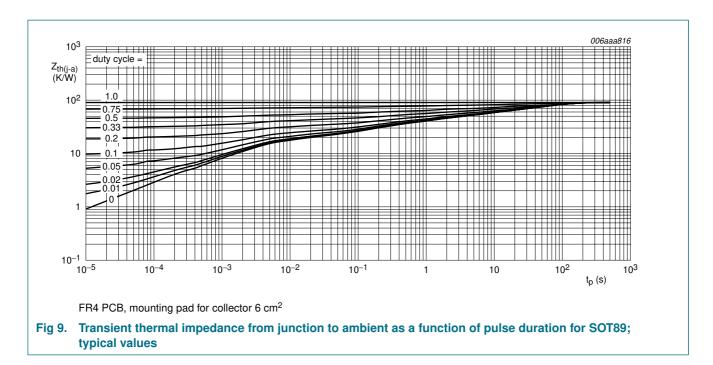
Fig 7. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values



FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>

Fig 8. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

8 of 15



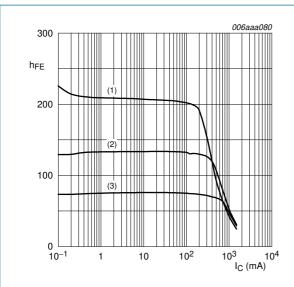
#### 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$		_	- 71	100	nA
OBO	current	$V_{CB} = 30 \text{ V}; I_{E} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$		-	-	10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V					
		$I_C = 5 \text{ mA}$		63	-	-	
		I <sub>C</sub> = 150 mA		63	-	250	
		I <sub>C</sub> = 500 mA	<u>[1]</u>	40	-	-	
	DC current gain	V <sub>CE</sub> = 2 V					
	h <sub>FE</sub> selection -10	I <sub>C</sub> = 150 mA		63	-	160	
	h <sub>FE</sub> selection -16	I <sub>C</sub> = 150 mA		100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$	[1]	-	-	500	mV
$V_{BE}$	base-emitter voltage	$V_{CE} = 2 \text{ V}; I_{C} = 500 \text{ mA}$	<u>[1]</u>	-	-	1	V
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz		-	6	-	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA};$ f = 100 MHz		100	180	-	MHz

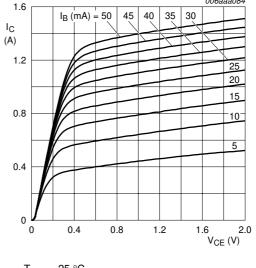
<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta = 0.02$ .



$$V_{CE} = 2 V$$

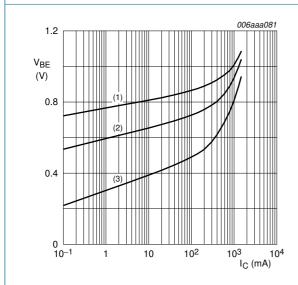
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 10. DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

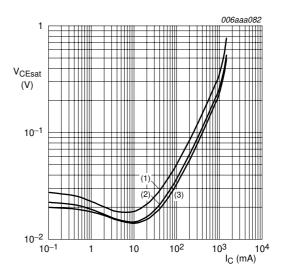
Fig 11. Collector current as a function of collector-emitter voltage; typical values





- (1)  $T_{amb} = -55 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \,^{\circ}C$
- (3)  $T_{amb} = 150 \, ^{\circ}C$

Fig 12. Base-emitter voltage as a function of collector current; typical values

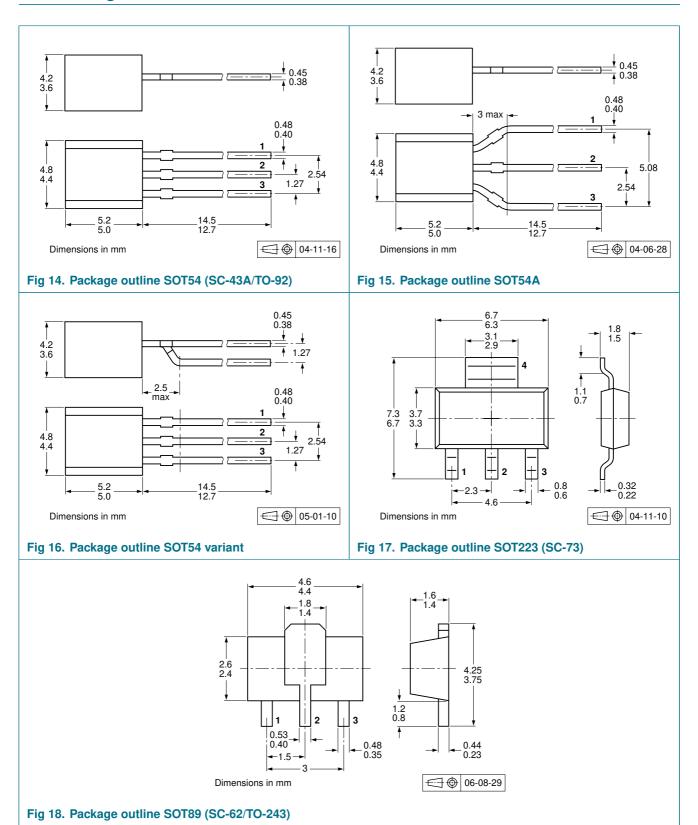


$$I_{\rm C}/I_{\rm B} = 10$$

- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 13. Collector-emitter saturation voltage as a function of collector current; typical values

# 8. Package outline



# 9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number[2]	Package	Description	Packing	Packing quantity			
			1000	4000	5000	10000	
BC639	SOT54	bulk, straight leads	-	-	-412	-	
SOT54A		tape and reel, wide pitch	-	-	-	-116	
		tape ammopack, wide pitch	-	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-	-112	-	
BCP56	SOT223	8 mm pitch, 12 mm tape and reel	-115	-135	-	-	
BCX56	SOT89	8 mm pitch, 12 mm tape and reel; T1	<u>3</u> -115	-135	-	-	
		8 mm pitch, 12 mm tape and reel; T3	<u>[4]</u> -120	-	-	-	

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.

<sup>[2]</sup> Valid for all available selection groups.

<sup>[3]</sup> T1: normal taping

<sup>[4]</sup> T3: 90° rotated taping

# 10. Revision history

#### Table 10. Revision history

Release date	Data sheet status	Change notice	Supersedes
20070622	Product data sheet	-	BC639_BCP56_BCX56_7
		edesigned to comply	with the new identity
<ul> <li>Legal texts</li> </ul>	have been adapted to the ne	w company name wl	nere appropriate.
<ul> <li><u>Table 1 "Pro</u></li> </ul>	oduct overview": amended		
• Section 1.2	"Features": amended		
• Section 1.3	"Applications": amended		
			lector current
<ul> <li>Table 2 "Qu</li> </ul>	ick reference data": I <sub>CM</sub> cond	ition added	
	<del>-</del>		
			current
	• ,		from junction to ambient
		duration	
	• ,		from junction to ambient
		duration	
	• ,		from junction to ambient
		duration	
		I DOV.50	
		method for BCX56	added
			DOGGO DODEC DOVEC C
		-	BC639_BCP56_BCX56_6
20050303	Product data sneet	CPCN200405029	BC635_637_639_4 BCP54_55_56_5
			BCX54_55_56_4
20011010	Product specification	-	BC635_637_639_3
20030206	Product specification	-	BCP54_55_56_4
20011010	Product specification	-	BCX54_55_56_3
	Table 1 "Produce of the second state of the se	<ul> <li>The format of this data sheet has been reguidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the need to be a section 1.2 "Features": amended</li> <li>Section 1.3 "Applications": amended</li> <li>Section 1.3 "Applications": amended</li> <li>Table 2 "Quick reference data": I<sub>C</sub> parameter regulated to "Limiting values": I<sub>C</sub> parameter regulated to "Table 6 "Limiting values": I<sub>C</sub> parameter regulated to "Table 7 "Thermal characteristics": Rth(j-a) transient is rigure 4: I<sub>p</sub> parameter redefined to pulse is rigure 5: added</li> <li>Figure 6: I<sub>p</sub> parameter redefined to pulse is rigure 6: I<sub>p</sub> parameter redefined to pulse is rigure 8: I<sub>p</sub> parameter redefined to pulse is rigure 9: added</li> <li>Figure 8: I<sub>p</sub> parameter redefined to pulse is rigure 9: added</li> <li>Figure 4: I<sub>p</sub> parameter redefined to pulse is rigure 9: added</li> <li>Figure 9: added</li> <li>Figure 4: I<sub>p</sub> parameter redefined to pulse is rigured at the pa</li></ul>	The format of this data sheet has been redesigned to comply guidelines of NXP Semiconductors.  Legal texts have been adapted to the new company name with table 1 "Product overview": amended  Section 1.2 "Features": amended  Section 1.3 "Applications": amended  Table 2 "Quick reference data": I <sub>C</sub> parameter redefined to colon table 2 "Quick reference data": I <sub>C</sub> parameter redefined to colon table 2 "Quick reference data": I <sub>C</sub> parameter redefined to collector  Table 6 "Limiting values": I <sub>C</sub> parameter redefined to collector  Table 6 "Limiting values": I <sub>C</sub> parameter redefined to collector  Table 6 "Limiting values": I <sub>C</sub> parameter redefined to collector  Table 6 "Limiting values": I <sub>C</sub> parameter redefined to collector  Table 7 "Thermal characteristics": R <sub>th(j-a)</sub> values for BCP56 and BCX56 at the figure 4: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 4: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 6: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 6: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 6: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 8: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 8: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 8: Z <sub>th</sub> redefined to Z <sub>th(j-a)</sub> transient thermal impedance  Figure 9: added  Figure 1: amended  Table 9 "Packing methods": new packing method for BCX56 at Section 11 "Legal information": updated  20050308 Product data sheet  CPCN200405029

#### 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

#### 11.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

#### 11.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

#### 11.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

#### 12. Contact information

For additional information, please visit: http://www.nxp.com

For sales office addresses, send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

BC639\_BCP56\_BCX56\_8 © NXP B.V. 2007. All rights reserved.

#### 13. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications 1
1.4	Quick reference data
2	Pinning information
3	Ordering information
4	Marking 3
5	Limiting values4
6	Thermal characteristics 6
7	Characteristics9
8	Package outline
9	Packing information 12
10	Revision history
11	Legal information 14
11.1	Data sheet status
11.2	Definitions
11.3	Disclaimers
11.4	Trademarks14
12	Contact information
13	Contents 15

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

